Quad MECL-to-TTL Translator

The MC10H125 is a quad translator for interfacing data and control signals between the MECL section and saturated logic section of digital systems. The 10H part is a functional/pinout duplication of the standard MECL 10K family part, with 100% improvement in propagation delay, and no increase in power-supply current.

Outputs of unused translators will go to low state when their inputs are left open.

- Propagation Delay, 2.5 ns Typical
- Voltage Compensated
- Improved Noise Margin 150 mV (Over Operating Voltage and Temperature Range)
- MECL 10K-Compatible



http://onsemi.com



CDIP CASE 620A

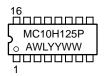


MARKING

DIAGRAMS



PDIP-16 P SUFFIX CASE 648





PLCC-20 FN SUFFIX CASE 775





EIAJ-16 M SUFFIX CASE 966

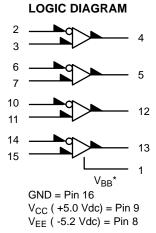


A = Assembly Location

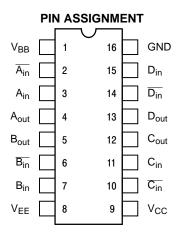
WL = Wafer Lot YY = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping		
MC10H125L	CDIP	25 Units/Rail		
MC10H125P	PDIP-16	25 Units/Rail		
MC10H125FN	PLCC-20	46 Units/Rail		
MC10H125M	EIAJ-16	50 Units/Rail		
MC10H125MEL	EIAJ-16	2000 Units/Reel		



 $^{^{*}}V_{BB}$ to be used to supply bias to the MC10H125 only and bypassed (when used) with 0.01 μF to 0.1 μF capacitor to ground (0 V). V_{BB} can source < 1.0 mA.



Pin assignment is for Dual-in-Line Package. For PLCC pin assignment, see the Pin Conversion Tables.

DIP CONVERSION TABLES

16-Pin DIL to 20-Pin PLCC

16 PIN DIL	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
20 PIN PLCC	2	3	4	5	7	8	9	10	12	13	14	15	17	18	19	20

20-Pin DIL to 20-Pin PLCC

20 PIN DIL	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	l
20 PIN PLCC	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18	19	20	

MAXIMUM RATINGS

Symbol	Characteristic	Rating	Unit
V _{EE}	Power Supply (V _{CC} = 5.0 V)	-8.0 to 0	Vdc
V _{CC}	Power Supply (V _{EE} = -5.2 V)	0 to +7.0	Vdc
VI	Input Voltage (V _{CC} = 5.0 V)	0 to V _{EE}	Vdc
T _A	Operating Temperature Range	0 to +75	°C
T _{stg}	Storage Temperature Range - Plastic - Ceramic	-55 to +150 -55 to +165	°C °C

ELECTRICAL CHARACTERISTICS (V_{EE} = -5.2 V +5%; V_{CC} = 5.0 V + 5.0 %) (Note 2)

		(O °	2	5°			
Symbol	Characteristic	Min	Max	Min	Max	Min	Max	Unit
Ι _Ε	Negative Power Supply Drain Current	-	44	-	40	-	44	mA
I _{CCH}	Positive Power Supply	=	63	-	63	-	63	mA
I _{CCL}	Drain Current	-	40	-	40	-	40	mA
I _{inH}	Input Current	-	225	-	145	-	145	μΑ
I _{CBO}	Input Leakage Current	-	1.5	-	1.0	-	1.0	μΑ
V _{OH}	High Output Voltage I _{OH} = -1.0 mA	2.5	-	2.5	-	2.5	-	Vdc
V_{OL}	Low Output Voltage I _{OL} = +20 mA	-	0.5	-	0.5	-	0.5	Vdc
V _{IH}	High Input Voltage (Note 1)	-1.17	-0.84	-1.13	-0.81	-1.07	-0.735	Vdc
V _{IL}	Low Input Voltage (Note 1)	-1.95	-1.48	-1.95	-1.48	-1.95	-1.45	Vdc
I _{OS}	Short Circuit Current	60	150	60	150	50	150	mA
V_{BB}	Reference Voltage	-1.38	-1.27	-1.35	-1.25	-1.31	-1.19	Vdc
V_{CMR}	Common Mode Range (Note 3)	-	-	-2.85	to +0.3			V
		Typical						
V_{PP}	Input Sensitivity (Note 4)	150						mV

AC PARAMETERS

			0	0	25 °		7		
Sym	nbol	Characteristic	Min	Max	Min	Max	Min	Max	Unit
tp	od	Propagation Delay	0.8	3.3	0.85	3.35	0.9	3.4	ns
t _r	r	Rise Time (Note 5)	0.3	1.2	0.3	1.2	0.3	1.2	ns
t _f	f	Fall Time (Note 5)	0.3	1.2	0.3	1.2	0.3	1.2	ns

^{1.} When V_{BB} is used as the reference voltage.

^{2.} Each MECL 10H series circuit has been designed to meet the specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is

^{3.} Differential input not to exceed 1.0 Vdc.

 ¹⁵⁰ mV_{p-p} differential input required to obtain full logic swing on output.
 Output Voltage = 1.0 V to 2.0 V. R_L = 500 Ω to GND and C_L = 25 pF to GND. Refer to Figure 1.

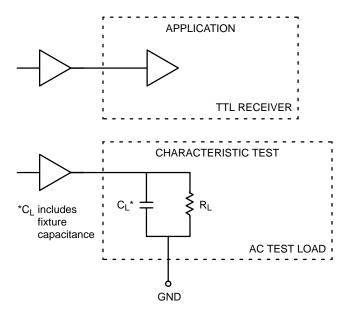


Figure 1. TTL Output Loading Used for Device Evaluation

APPLICATION INFORMATION

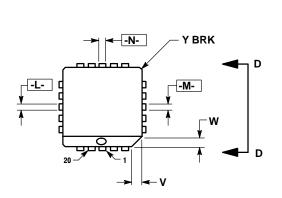
The MC10H125 incorporates differential inputs and Schottky TTL "totem pole" outputs. Differential inputs allow for use as an inverting/non-inverting translator or as a differential line receiver. The V_{BB} reference voltage is available on Pin 1 for use in single-ended input biasing. The outputs of the MC10H125 go to a low-logic level whenever the inputs are left floating, and a high-logic output level is achieved with a minimum input level of 150 mV_{p-p}.

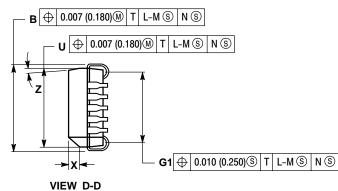
An advantage of this device is that MECL-level information can be received, via balanced twisted pair lines, in the TTL equipment. This isolates the MECL-logic from the noisy TTL environment. Power supply requirements are ground, +5.0 volts and -5.2 volts.

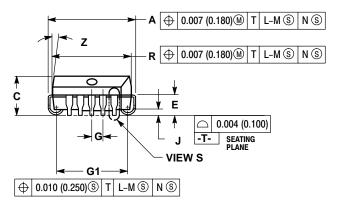
PACKAGE DIMENSIONS

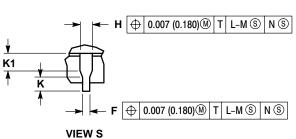
PLCC-20 **FN SUFFIX**

PLASTIC PLCC PACKAGE CASE 775-02 ISSUE D









NOTES:

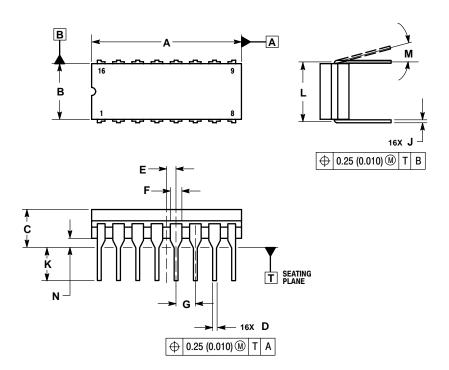
- DATUMS -L-, -M-, AND -N- DETERMINED
 WHERE TOP OF LEAD SHOULDER EXITS PLASTIC
 BODY AT MOLD PARTING LINE.
- DIMENSION G1, TRUE POSITION TO BE MEASURED AT DATUM -T-, SEATING PLANE.
 DIMENSIONS R AND U DO NOT INCLUDE MOLD.
- 3. DIMENSIONS I AND U DO NOT INCLUDE MOLD FLASH. ALLOWABLE MOLD FLASH IS 0.010 (0.250) PER SIDE.
 4. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 5. CONTROLLING DIMENSION: INCH.
 6. THE PACKAGE TOP MAY BE SMALLER THAN THE

- PACKAGE BOTTOM BY UP TO 0.012 (0.300).
 DIMENSIONS R AND U ARE DETERMINED AT THE
 OUTERMOST EXTREMES OF THE PLASTIC BODY
 EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS,
- EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY.

 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.385	0.395	9.78	10.03
В	0.385	0.395	9.78	10.03
С	0.165	0.180	4.20	4.57
Е	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.350	0.356	8.89	9.04
U	0.350	0.356	8.89	9.04
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
Х	0.042	0.056	1.07	1.42
Υ		0.020		0.50
Z	2°	10°	2 °	10 °
G1	0.310	0.330	7.88	8.38
K1	0.040		1.02	

CDIP CASE 620A-01 ISSUE O



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: INCH.

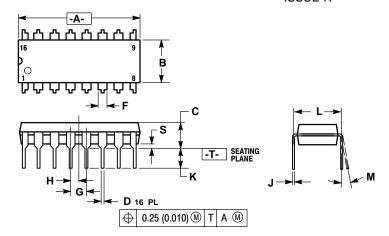
 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL

 4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

 5. THIS DRAWING REPLACES OBSOLETE CASE OUTLINE 620-10.

	INC	HES	MILLIMETERS				
DIM	MIN	MAX	MIN	MAX			
Α	0.750	0.785	19.05	19.93			
В	0.240	0.295	6.10	7.49			
C		0.200		5.08			
D	0.015	0.020	0.39	0.50			
E	0.050	BSC	1.27 BSC				
F	0.055	0.065	1.40	1.65			
G	0.100	BSC	2.54 BSC				
Н	0.008	0.015	0.21	0.38			
K	0.125	0.170	3.18	4.31			
L	0.300		7.62	BSC			
M	0°	15°	0 °	15°			
N	0.020	0.040	0.51	1.01			

PDIP-16 P SUFFIX PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



NOTES:

- VOIES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN
- FORMED PARALLEL.
 DIMENSION B DOES NOT INCLUDE MOLD FLASH.
- ROUNDED CORNERS OPTIONAL.

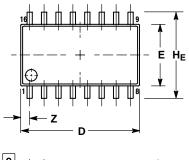
	INC	HES	MILLIN	IETERS		
DIM	MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
C	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	BSC	2.54 BSC			
Н	0.050	BSC	1.27 BSC			
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
M	0°	10°	0°	10 °		
S	0.020	0.040	0.51	1.01		

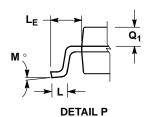
STYLE 1: PIN 1.

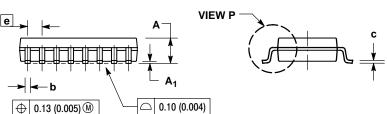
CATHODE

- 2
- CATHODE 3.
- CATHODE
- CATHODE CATHODE
- 6. 7. CATHODE
- CATHODE
- ANODE ANODE 9. 10.
- ANODE ANODE ANODE 11. 12. 13.
- ANODE
- ANODE ANODE 15. 16.

EIAJ-16 **M SUFFIX** 16 PIN PLASTIC EIAJ PACKAGE CASE966-01 **ISSUE O**







- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTHUSION: ALLOWABLE
 DAMBAR PROTHUSION SHALL BE 0.08 (0.003)
 TOTAL IN EXCESS OF THE LEAD WIDTH
 DIMENSION AT MAXIMUM MATERIAL CONDITION.
 DAMBAR CANNOT BE LOCATED ON THE LOWER
 RADIUS OR THE FOOT. MINIMUM SPACE
 BETWEEN PROTRUSIONS AND ADJACENT LEAD

	•	,					
	MILLIN	IETERS	INCHES				
DIM	MIN	MAX	MIN	MAX			
Α		2.05		0.081			
A ₁	0.05	0.20	0.002	0.008			
b	0.35	0.50	0.014	0.020			
C	0.18	0.27	0.007	0.011			
D	9.90	10.50	0.390	0.413			
E	5.10	5.45	0.201	0.215			
е	1.27	BSC	0.050 BSC				
HE	7.40	8.20	0.291	0.323			
L	0.50	0.85	0.020	0.033			
LE	1.10	1.50	0.043	0.059			
M	0 °	10°	0 °	10 °			
Q ₁	0.70	0.90	0.028	0.035			
Z		0.78		0.031			

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